74ABT16821A

20-bit bus-interface D-type flip-flop; positive-edge trigger; 3-state

Rev. 03 — 16 March 2010

Product data sheet

1. General description

The 74ABT16821A high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16821A has two 10-bit, edge-triggered registers, with each register coupled to a 3-state output buffer. The two sections of each register are controlled independently by the clock (nCP) and output enable (nOE) control gates.

Each register is fully edge triggered. The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flops Q output.

The 3-state output buffers are designed to drive heavily loaded 3-state buses, MOS memories, or MOS microprocessors.

The active-LOW output enable ($n\overline{OE}$) controls all ten 3-state buffers independent of the register operation. When $n\overline{OE}$ is LOW, the data in the register appears at the outputs. When $n\overline{OE}$ is HIGH, the outputs are in high-impedance OFF-state, which means they will neither drive nor load the bus.

2. Features and benefits

- 20-bit positive-edge triggered register
- Multiple V_{CC} and GND pins minimize switching noise
- Live insertion and extraction permitted
- Output capability: +64 mA and -32 mA
- Power-up 3-state
- Power-up reset
- Latch-up protection exceeds 500 mA per JESD78B class II level A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V

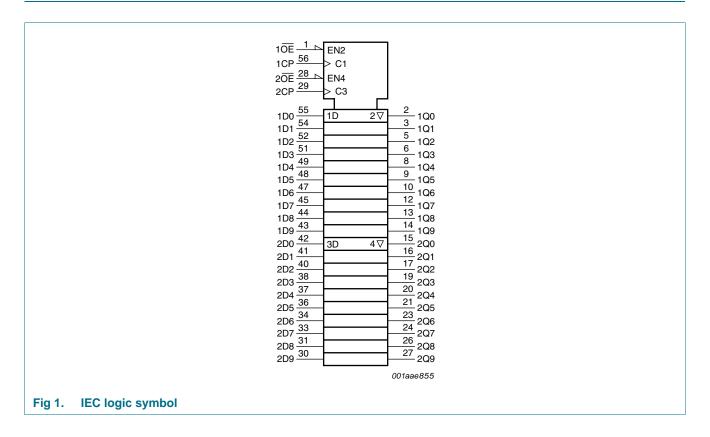


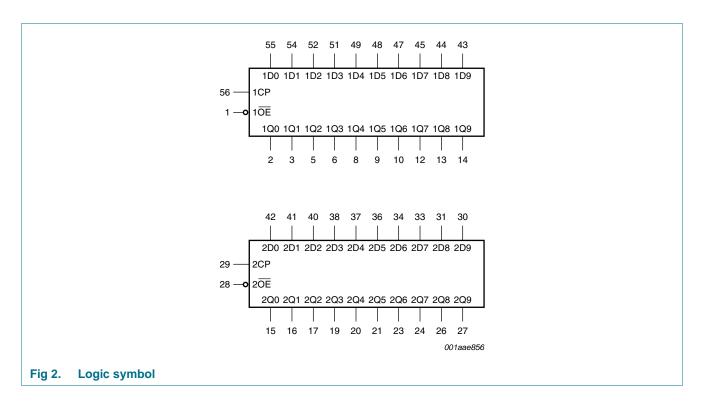
3. Ordering information

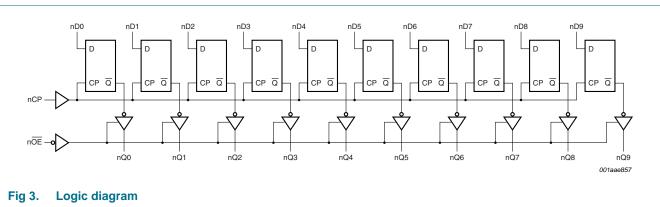
Table 1. Ordering information

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74ABT16821ADL	–40 °C to +85 °C	SSOP56	plastic shrink small outline package; 56 leads; body width 7.5 mm	SOT371-1						
74ABT16821ADGG	–40 °C to +85 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 6.1 mm	SOT364-1						

4. Functional diagram

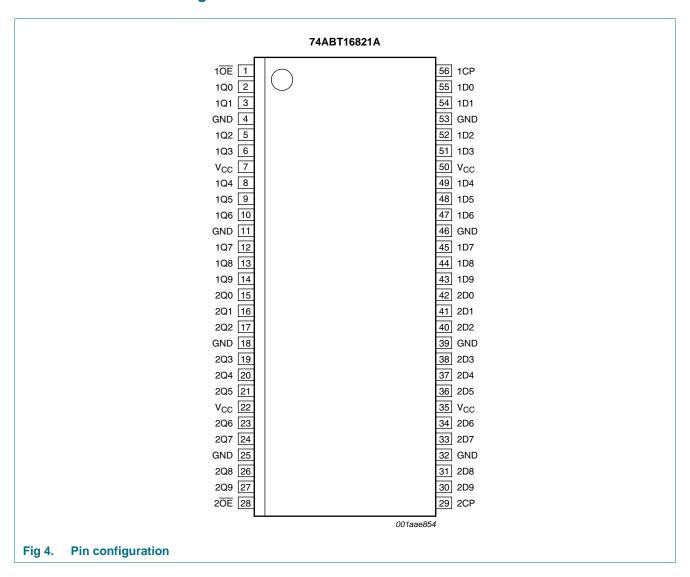






5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1 OE , 2 OE	1, 28	output enable input (active LOW)
1Q0 to 1Q9	2, 3, 5, 6, 8, 9, 10, 12, 13, 14	data output
GND	4, 11, 18, 25, 32, 39, 46, 53	ground (0 V)
V _{CC}	7, 22, 35, 50	supply voltage
2Q0 to 2Q9	15, 16, 17, 19, 20, 21, 23, 24, 26, 27	data output
2CP, 1CP	29, 56	clock pulse input (active rising edge)
2D0 to 2D9	42, 41, 40, 38, 37, 36, 34, 33, 31, 30	data input
1D0 to1D9	55, 54, 52, 51, 49, 48, 47, 45, 44, 43	data input

6. Functional description

Table 3. Function table[1]

Input			Output	Internal register	Operating mode
nOE	nCP	nDx	nQ0 to nQ9		
L	\uparrow	1	L	L	load + read register
L	↑	h	Н	Н	load + read register
L	H or L	X	NC	NC	hold
Н	L or H	X	Z	NC	disable output
Н	↑	Dn	Z	Dn	disable output

[1] H = HIGH voltage level;

 $h = HIGH \ voltage \ level \ one \ set-up \ time \ prior \ to \ the \ LOW-to-HIGH \ clock \ transition;$

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

↑ = LOW-to-HIGH clock transition;

NC = no change;

X = don't care;

Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		<u>[1]</u> –1.2	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state	<u>[1]</u> –0.5	+5.5	V
I _{IK}	input clamping current	V _I < 0 V	–18	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Io	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-64	-	mA
Tj	junction temperature		[2] _	150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		4.5	-	5.5	V
VI	input voltage		0	-	V_{CC}	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level Input voltage		-	-	0.8	V
I _{OH}	HIGH-level output current		-32	-	-	mA
I _{OL}	LOW-level output current		-	-	64	mA
$\Delta t/\Delta V$	input transition rise and fall rate		0	-	10	ns/V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

9. Static characteristics

Table 6. Static characteristics

Symbol	Parameter	Conditions			25 °C		-40 °C to +85 °C		Unit
				Min	Тур	Max	Min	Max	
V _{IK}	input clamping voltage	$V_{CC} = 4.5 \text{ V}; I_{IK} = -18 \text{ mA}$		-1.2	-0.9	-	-1.2	-	V
V _{OH}	HIGH-level output	$V_I = V_{IL}$ or V_{IH}							
	voltage	$V_{CC} = 4.5 \text{ V}; I_{OH} = -3 \text{ mA}$		2.5	2.9	-	2.5	-	V
		$V_{CC} = 5.0 \text{ V}; I_{OH} = -3 \text{ mA}$		3.0	3.4	-	3.0	-	V
		$V_{CC} = 4.5 \text{ V}; I_{OH} = -32 \text{ mA}$		2.0	2.4	-	2.0	-	V
V_{OL}	LOW-level output voltage	V_{CC} = 4.5 V; I_{OL} = 64 mA; V_I = V_{IL} or V_{IH}		-	0.36	0.55	-	0.55	V
$V_{OL(pu)}$	power-up LOW-level output voltage	V_{CC} = 5.5 V; I_O = 1 mA; V_I = GND or V_{CC}	[1]	-	0.13	0.55	-	0.55	V
I _I	input leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{CC} \text{ or GND}$		-	±0.01	±1.0	-	±1.0	μΑ
I _{OFF}	power-off leakage current	V_{CC} = 0 V; V_{I} or $V_{O} \le 4.5$ V		-	±5.0	±100	-	±100	μΑ
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} = 2.1 \text{ V}; V_O = 0.5 \text{ V};$ $V_I = \text{GND or } V_{CC}; n\overline{\text{OE}} \text{ don't care}$	[2]	-	±5.0	±50	-	±50	μΑ
I _{OZ}	OFF-state output	$V_{CC} = 5.5 \text{ V}; V_I = V_{IL} \text{ or } V_{IH}$							
	current	output HIGH-state at $V_0 = 2.7 \text{ V}$		-	1.0	10	-	10	μΑ
		output LOW-state at $V_O = 0.5 \text{ V}$		-	-1.0	-10	-	-10	μΑ
I_{LO}	output leakage current	HIGH-state; $V_O = 5.5 \text{ V}$; $V_{CC} = 5.5 \text{ V}$; $V_I = \text{GND or } V_{CC}$		-	5.0	50	-	50	μΑ
Io	output current	$V_{CC} = 5.5 \text{ V}; V_{O} = 2.5 \text{ V}$	[3]	-180	-90	-50	-180	-50	mΑ
I _{CC}	supply current	V_{CC} = 5.5 V; V_I = GND or V_{CC}							
		outputs HIGH-state		-	0.5	1.0	-	1.0	mΑ
		outputs LOW-state		-	10	19	-	19	mΑ
		outputs 3-state		-	0.5	1.0	-	1.0	mΑ
ΔI_{CC}	additional supply current	per input pin; V_{CC} = 5.5 V; one input at 3.4 V and other inputs at V_{CC} or GND	<u>[4]</u>	-	0.25	1.5	-	1.5	mA
Cı	input capacitance	$V_I = 0 \text{ V or } V_{CC}$		-	3	-	-	-	
Co	output capacitance	outputs disabled; $V_O = 0 \text{ V or } V_{CC}$		-	7	-	-	-	

^[1] For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.

^[2] This parameter is valid for any V_{CC} between 0 V and 2.1 V, with a transition time of up to 10 ms. From V_{CC} = 2.1 V to V_{CC} = 5 V \pm 10 % a transition time of up to 100 μ s is permitted.

^[3] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

^[4] This is the increase in supply current for each input at 3.4 V.

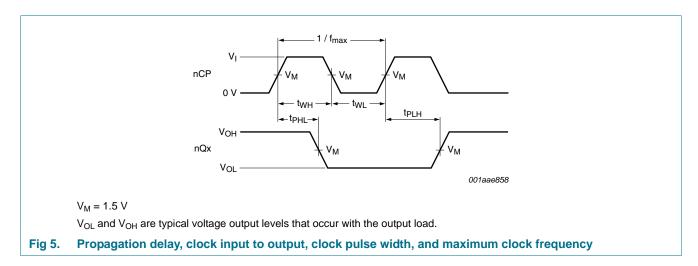
10. Dynamic characteristics

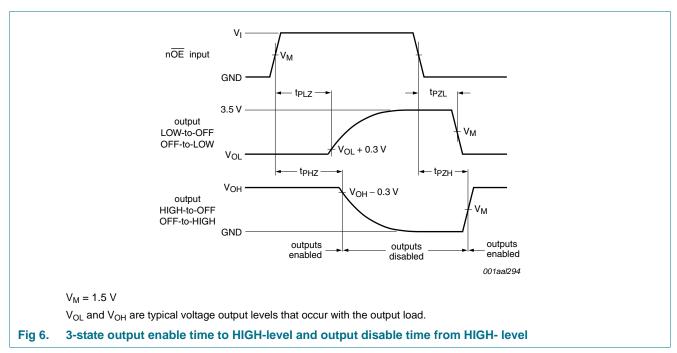
Table 7. Dynamic characteristics

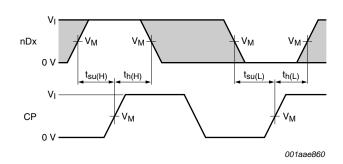
GND = 0 V; for test circuit, see Figure 8.

Symbol	Parameter	Conditions	25 °C	; V _{CC} =	5.0 V	-40 °C to +85 °C; V_{CC} = 5.0 V \pm 0.5 V		Unit
			Min	Тур	Max	Min	Max	
f _{max}	maximum frequency	see Figure 5	160	250	-	160	-	MHz
t _{PLH}	LOW to HIGH propagation delay	nCP to nQx, see Figure 5	1.3	2.4	3.3	1.3	3.7	ns
t _{PHL}	HIGH to LOW propagation delay	nCP to nQx, see Figure 5	1.1	2.0	2.6	1.1	3.0	ns
t _{PZH}	OFF-state to HIGH propagation delay	nOE to nQx; see Figure 6	1.4	2.5	3.3	1.4	4.1	ns
t _{PZL}	OFF-state to LOW propagation delay	nOE to nQx; see Figure 6	1.2	2.3	3.0	1.2	3.7	ns
t _{PHZ}	HIGH to OFF-state propagation delay	nOE to nQx; see Figure 6	1.6	3.2	4.1	1.6	4.8	ns
t_{PLZ}	LOW to OFF-state propagation delay	nOE to nQx; see Figure 6	1.3	2.3	3.1	1.3	3.3	ns
t _{su(H)}	set-up time HIGH	nDx to nCP; see Figure 7	1.8	1.2	-	1.8	-	ns
t _{su(L)}	set-up time LOW	nDx to nCP; see Figure 7	+1.8	-0.9	-	+1.8	-	ns
t _{h(H)}	hold time HIGH	nDx to nCP; see Figure 7	1.0	8.0	-	1.0	-	ns
t _{h(L)}	hold time LOW	nDx to nCP; see Figure 7	+1.0	-1.0	-	+1.0	-	ns
t _{WH}	pulse width HIGH	nCP; see Figure 5	2.5	8.0	-	2.5	-	ns
t_{WL}	pulse width LOW	nCP; see Figure 5	2.5	1.0	-	2.5	-	ns

11. Waveforms



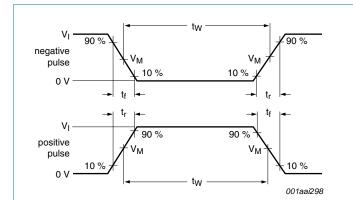


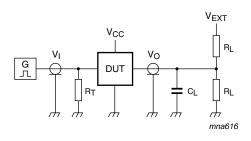


The shaded areas indicate when the input is permitted to change for predictable output performance.

 $V_{M} = 1.5 \text{ V}$

Fig 7. Set-up and hold times data input (nDx) to clock (CP)





b. Test circuit

a. Input pulse definition

Test data is given in Table 8.

Definitions test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 8. Load circuitry for switching times

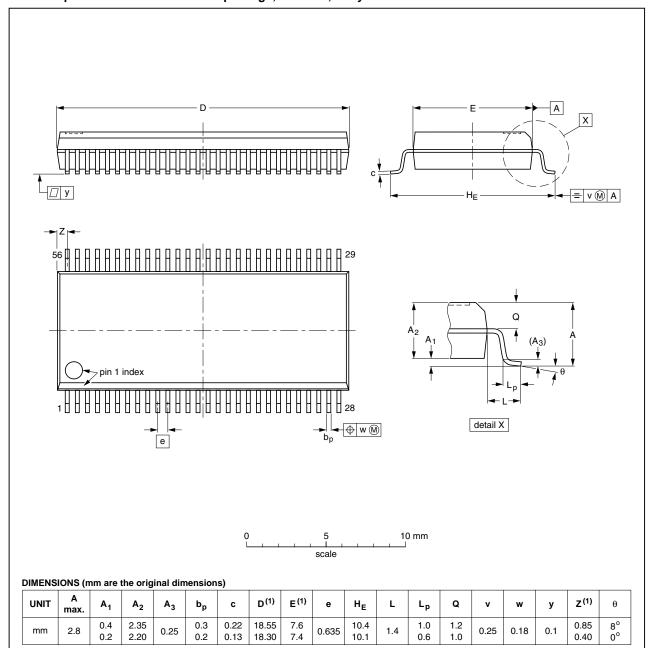
Table 8. Test data

Input				Load		V _{EXT}		
V_{I}	f _l	t _W	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
3.0 V	1 MHz	500 ns	≤ 2.5 ns	50 pF	500Ω	open	open	7.0 V

12. Package outline

SSOP56: plastic shrink small outline package; 56 leads; body width 7.5 mm

SOT371-1



Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT371-1		MO-118			99-12-27 03-02-18	

Fig 9. Package outline SOT371-1 (SSOP56)

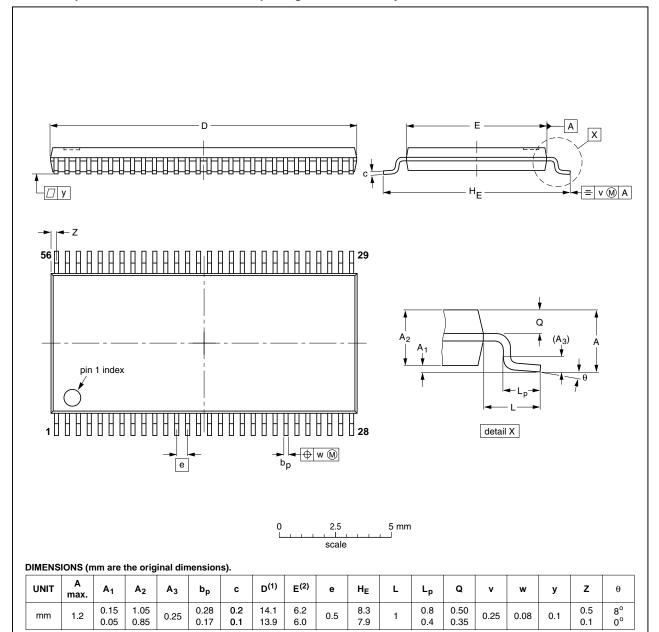
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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm

SOT364-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	KEFEK	ENCES		EUROPEAN ISSUE DAT	
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	MO-153				99-12-27 03-02-19
	IEC	IEC JEDEC	IEC JEDEC JEITA	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION

Fig 10. Package outline SOT364-1 (TSSOP56)

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13. Abbreviations

Table 9. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74ABT16821A_3	20100316	Product data sheet	-	74ABT_H16821A_2
Modifications:		of this data sheet has been re	designed to comply v	vith the new identity
	 Legal texts h 	ave been adapted to the new	company name whe	ere appropriate.
	 Type numbe 	r 74ABTH16821ADGG remo	ved from Section 3 "C	Ordering information".
74ABT_H16821A_2	20021213	Product specification	-	74ABT_H16821A
74ABT_H16821A	19980227	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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NXP Semiconductors 74ABT16821A

20-bit bus-interface D-type flip-flop; positive-edge trigger; 3-state

16. Contact information

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